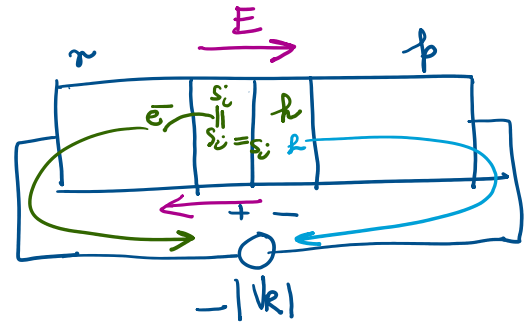
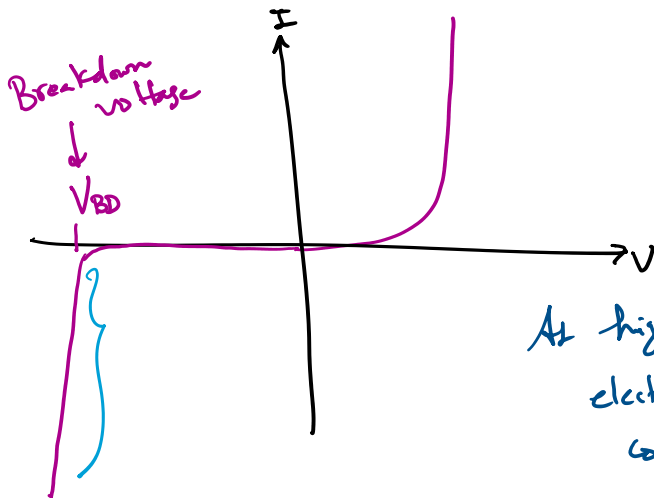


ma 11/16/29

ECE Ambassador Program

Reverse Breakdown



At high electric fields, the field can tear off electrons from the Si lattice by breaking covalent bonds

↳ Electrons flow in the opposite direction of the field

↳ large current flow.

Zener Breakdown

Avalanche Breakdown

↳ high doping levels on both n & p sides

Zener effect → $3-8V \leftarrow V_Z$
Zener voltage

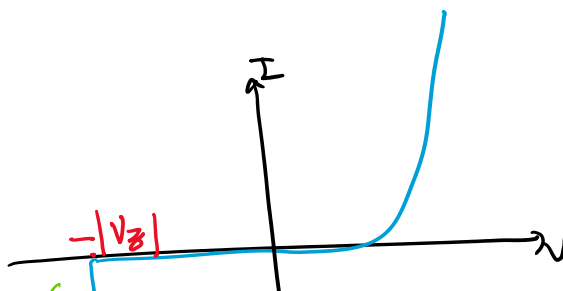
↳ low doping levels.

↳ $< 10^{15} \text{ cm}^{-3}$

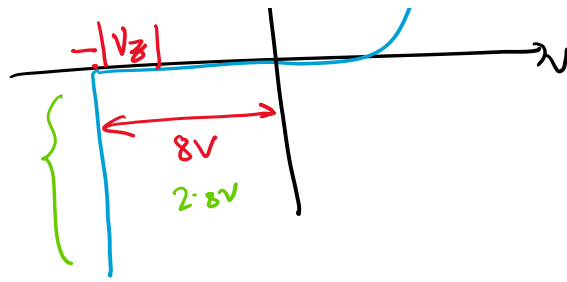
↳ chain reaction or multiplier effect

↳ impact ionization

* Effects are reversible unless large current melts the device.



Read Chapter 2



Read Chapter 2

Chapter 3

Friday, February 2, 2018 10:53 AM

Why diodes?

Ex. Cellphone charger:

Ac line voltage

We require

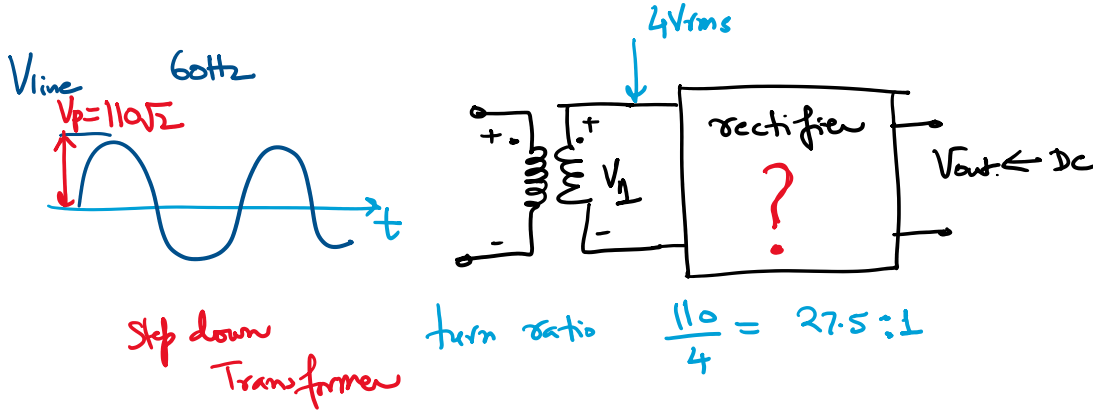
110V @ 60Hz

3.5V DC

Asia/EU

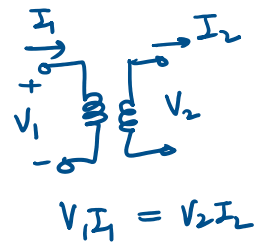
220V @ 50Hz

$$V_{rms} = \frac{V_p}{\sqrt{2}}$$



3.5V

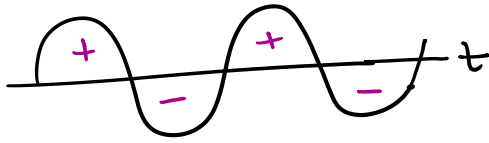
t



$$\frac{V_1}{V_2} = \frac{I_2}{I_1} \Leftarrow \text{turn ratio}$$

Transformer

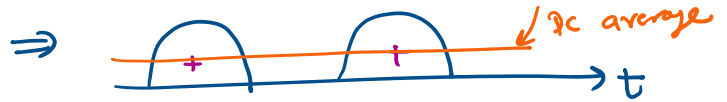
retain +ve half cycle



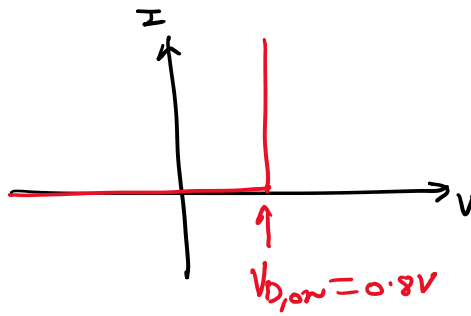
average $\Leftarrow DC = 0$

We use Diode \Rightarrow

Short for +ve voltages
open for -ve voltages

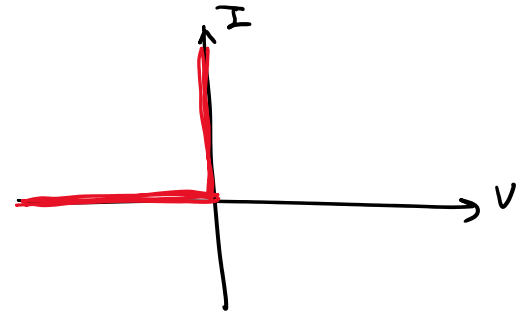


Constant voltage Diode (CVD)

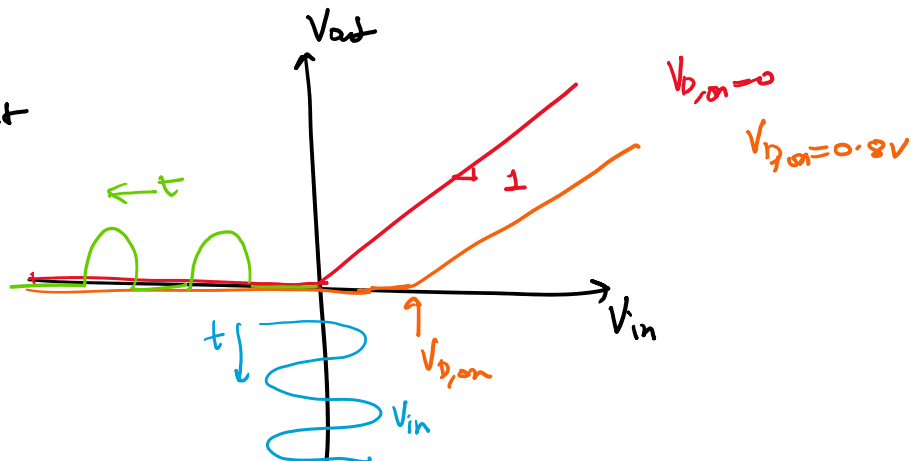
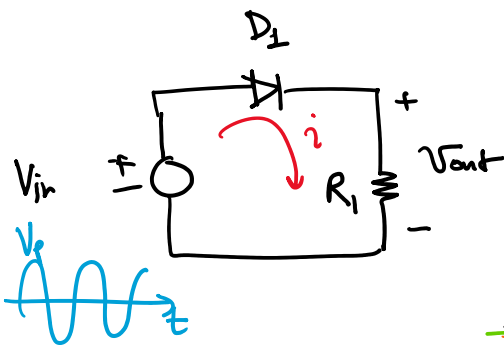


Ideal Diode

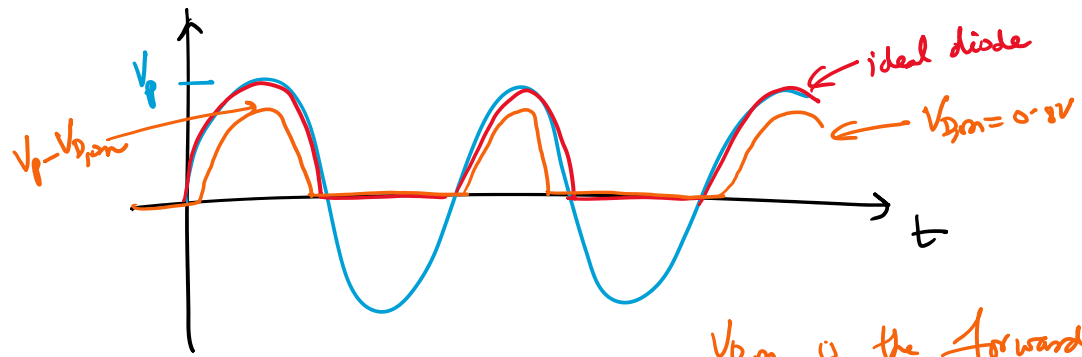
$V_{D,on} = 0$



Ideal Diode

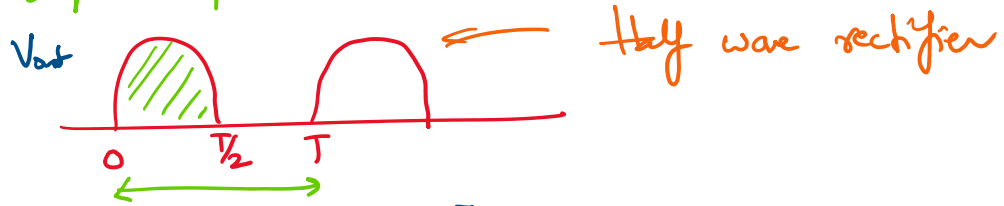


input/output characteristics



$V_{D(on)}$ is the forward voltage drop
 in the diode.

output waveform



$$V_{out, avg} = \frac{1}{T} \int_0^T V_{out}(t) dt = \frac{1}{T} \int_0^{T/2} V_p \sin(\omega t) dt$$

$$= \frac{1}{T} \frac{V_p}{\omega} [-\cos \omega t]_0^{T/2}$$

$$= \frac{V_p}{\pi} \leftarrow \text{average of DC content in the half wave rectified output}$$

